



Integrated Device Technology, Inc.

16 x 16 PARALLEL CMOS MULTIPLIERS

 IDT7216L
IDT7217L

T-45-07

FEATURES:

- 16 x 16 parallel multiplier with double precision product
- 20ns clocked multiply time
- Low power consumption: 120mA
- Produced with advanced submicron CEMOS™ high performance technology
- IDT7216L is pin- and function compatible with TRW MPY016H/K and AMD Am29516
- IDT7217L requires a single clock with register enables making it pin- and function compatible with AMD Am29517
- Configured for easy array expansion
- User-controlled option for transparent output register mode
- Round control for rounding the MSP
- Input and output directly TTL-compatible
- Three-state output
- Available in plastic and Top Braze, DIP, PLCC, Flatpack and Pin Grid Array
- Military product compliant to MIL-STD-883, Class B
- Standard Military Drawing #5962-86873 is listed on this function for IDT7216 and Standard Military Drawing #5962-87686 is listed for this function for IDT7217.
- Speeds available: Commercial: L20/25/35/45/55/65
Military: L25/30/40/55/65/75

DESCRIPTION:

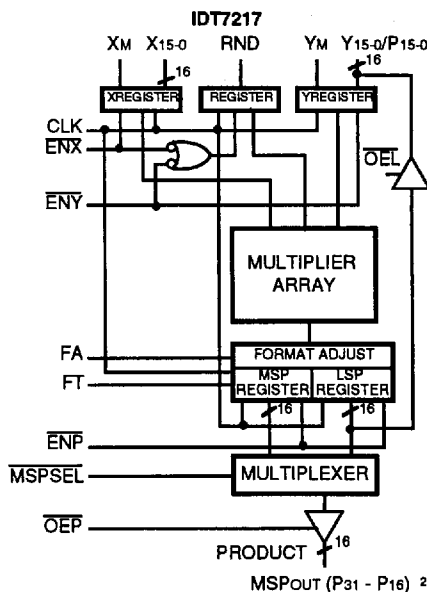
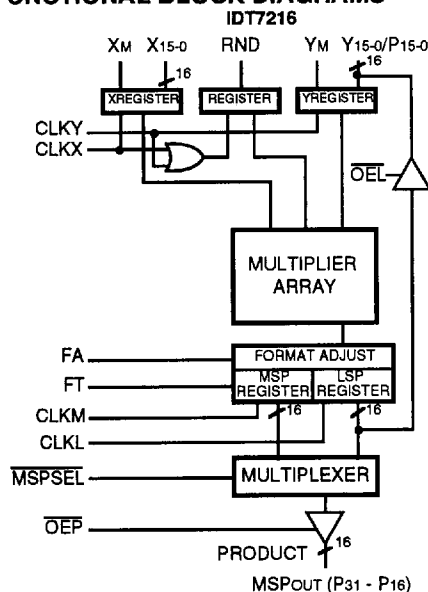
The IDT7216/IDT7217 are high-speed, low-power 16 x 16-bit multipliers ideal for fast, real time digital signal processing applications. Utilization of a modified Booths algorithm and IDT's high-performance, submicron CEMOS technology, has achieved speeds comparable to bipolar (20ns max.), at 1/10 the power consumption.

The IDT7216/IDT7217 are ideal for applications requiring high-speed multiplication such as fast Fourier transform analysis, digital filtering, graphic display systems, speech synthesis and recognition and in any system requirement where multiplication speeds of a mini/microcomputer are inadequate.

All input registers, as well as LSP and MSP output registers, use the same positive edge-triggered D-type flip-flop. In the IDT7216, there are independent clocks (CLKX, CLKY, CLKM, CLKL) associated with each of these registers. The IDT7217 has only a single clock input (CLK) and three register enables. ENX and ENY control the two input registers, while ENP controls the entire product.

The IDT7216/IDT7217 offer additional flexibility with the FA control and MSPSEL functions. The FA control formats the output for two's complement by shifting the MSP up one bit and then repeating the sign bit in the MSB of the LSP. The

FUNCTIONAL BLOCK DIAGRAMS



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MILITARY AND COMMERCIAL TEMPERATURE RANGES

MAY 1992

IDT7216L, IDT7217L

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MILITARY AND COMMERCIAL TEMPERATURE RANGES

DESCRIPTION (Cont'd.)

MSPSEL low selects the MSP to be available at the product output port, while a high selects the LSP to be available. Keeping this pin low will ensure compatibility with the TRW MPY016H.

The IDT7216/IDT7217 multipliers are manufactured in compliance with the latest revision of MIL-STD-883, Class B, making them ideally suited to applications demanding the highest level of performance and reliability.

PIN CONFIGURATIONS**IDT7216**

X4	1	64	X5
X3	2	63	X6
X2	3	62	X7
X1	4	61	X8
X0	5	60	X9
OEL	6	59	X10
CLKL	7	58	X11
CLKY	8	57	X12
P0, Y0	9	56	X13
P1, Y1	10	55	X14
P2, Y2	11	54	X15
P3, Y3	12	53	CLKX
P4, Y4	13	52	RND
P5, Y5	14	51	XM
P6, Y6	15	50	YM
P7, Y7	16	49	VCC
P8, Y8	17	48	VCC
P9, Y9	18	47	GND
P10, Y10	19	46	GND
P11, Y11	20	45	MSPSEL
P12, Y12	21	44	FT
P13, Y13	22	43	FA
P14, Y14	23	42	OEP
P15, Y15	24	41	CLKM
P0, P16	25	40	P15, P31
P1, P17	26	39	P14, P30
P2, P18	27	38	P13, P29
P3, P19	28	37	P12, P28
P4, P20	29	36	P11, P27
P5, P21	30	35	P10, P26
P6, P22	31	34	P9, P25
P7, P23	32	33	P8, P24

**64-PIN DIP
TOP VIEW**

2580 drw 03

IDT7217

X4	1	64	X5
X3	2	63	X6
X2	3	62	X7
X1	4	61	X8
X0	5	60	X9
OEL	6	59	X10
CLK	7	58	X11
ENY	8	57	X12
P0, Y0	9	56	X13
P1, Y1	10	55	X14
P2, Y2	11	54	X15
P3, Y3	12	53	ENX
P4, Y4	13	52	RND
P5, Y5	14	51	XM
P6, Y6	15	50	YM
P7, Y7	16	49	VCC
P8, Y8	17	48	VCC
P9, Y9	18	47	GND
P10, Y10	19	46	GND
P11, Y11	20	45	MSPSEL
P12, Y12	21	44	FT
P13, Y13	22	43	FA
P14, Y14	23	42	OEP
P15, Y15	24	41	ENP
P0, P16	25	40	P15, P31
P1, P17	26	39	P14, P30
P2, P18	27	38	P13, P29
P3, P19	28	37	P12, P28
P4, P20	29	36	P11, P27
P5, P21	30	35	P10, P26
P6, P22	31	34	P9, P25
P7, P23	32	33	P8, P24

**64-PIN DIP
TOP VIEW**

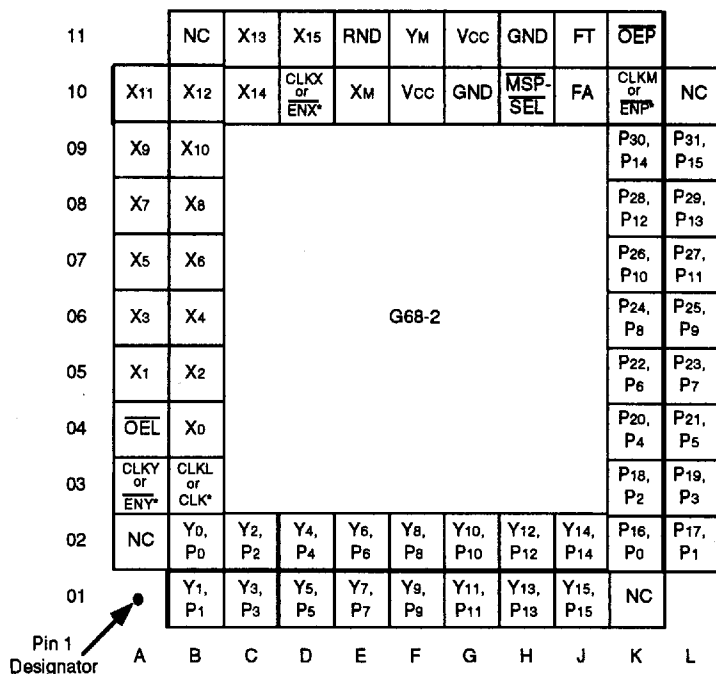
2580 drw 04

IDT7216L, IDT7217L
16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES

PIN CONFIGURATIONS (Cont'd.)

IDT7216/IDT7217



*Pin designation for IDT7217

PGA
TOP VIEW

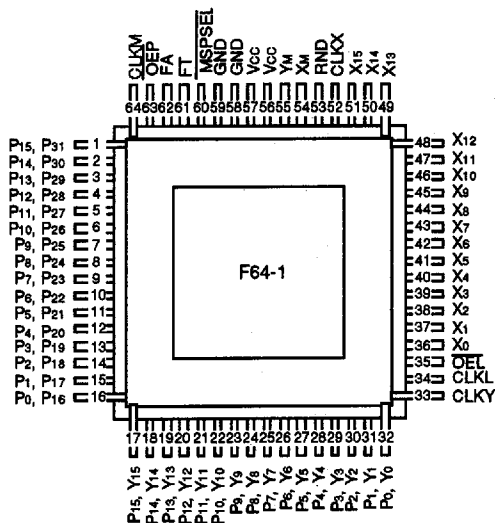
2580 drw 05

IDT7216L, IDT7217L
16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES

PIN CONFIGURATIONS (Cont'd.)

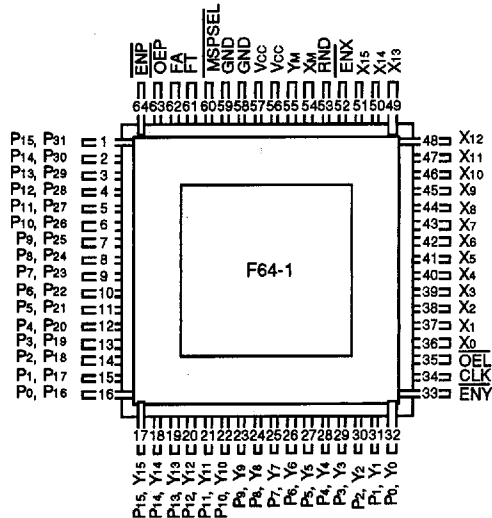
IDT7216



64-LEAD FLATPACK
TOP VIEW

2580 drw 06

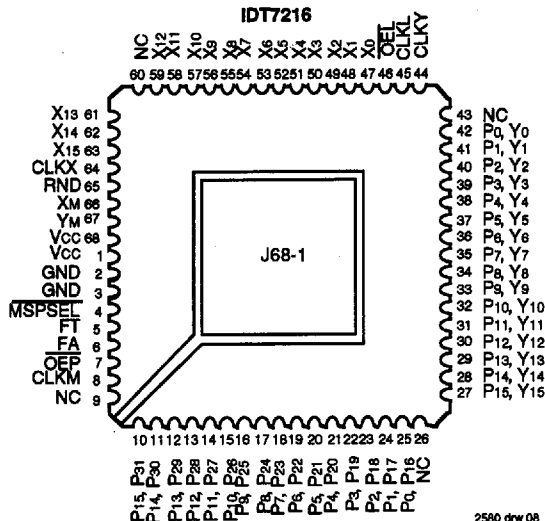
IDT7217



64-LEAD FLATPACK
TOP VIEW

2580 drw 07

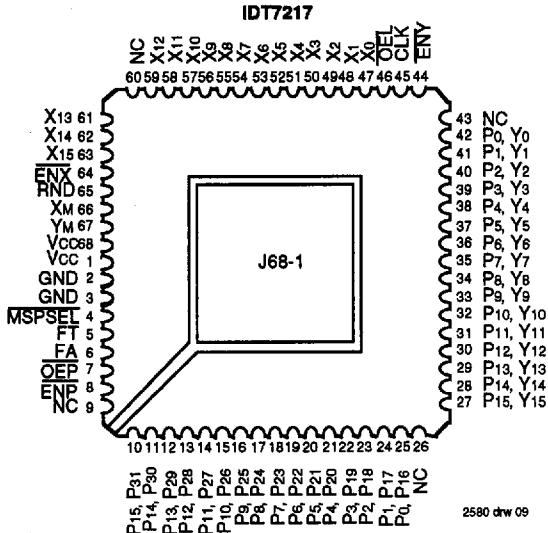
IDT7216



PLCC
TOP VIEW

2580 drw 08

IDT7217



PLCC
TOP VIEW

2580 drw 09

IDT7216L, IDT7217L

16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES

PIN DESCRIPTIONS

Pin Name	I/O	Description
X0 - X15	I	Data Inputs
Y0 - Y15/ P0 - P15	I/O	Y0 - Y15 are data inputs P0 - P15 are LSP register output, enabled when $\overline{OEL} = 0$
P16 - P31	O	Data Output (LSP or MSP)
$\overline{OEL}$	I	Output enable control for LSP (least significant product). When low enables P0 - P15. When high P0 - P15 tristated.
$\overline{OEP}$	I	Output enable control for MSP (most significant product). When low enables P16 - P31. When high P16 - P31 tristated.
Xm, Ym	I	Mode control for each data word. Low designates unsigned data input and high designates two's complement.
RND	I	"Round" control for rounding of MSP. When high, 1 is added to the most significant bit of LSP. This signal is affected by the state of FA pin. When FA = 1 and RND = 1, 1 is added to the 2^{-15} bit (P15). When RND = 1 and FA = 0, 1 is added to the 2^{-16} bit (P14). The RND input is registered. It is clocked on the rising edge of the logical OR of CLKX and CLKY in the 7216 and on the rising edge of CLK in the 7217. Rounding always occurs in the positive direction which may introduce a systematic bias.
MSPSEL	I	When low, MSP is output on P16 - P31 lines. When high, LSP is output on P16 - P31.
FA	I	Format adjust control. When high, a full 32 bit product is selected. When low, a left shifted 31 bit product is selected with the sign bit replicated in the LSP. FA is normally high, except for certain fractional two's complement applications (see multiplier input / output formats).
FT	I	Flow through control. When high, both MSP and LSP registers are by-passed.
CLK	I	7217 X, Y, RND, LSP and MSP register clock input.
CLKX	I	7216 X register clock input. Also clocks RND register.
CLKY	I	7216 Y register clock input. Also clocks RND register.
CLKL	I	7216 LSP register clock input.
CLKM	I	7216 MSP register clock input.
ENX	I	7217 X register clock enable. Also enables RND register clock.
ENY	I	7217 Y register clock enable. Also enables RND register clock.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Commercial	Military	Unit
VCC	Power Supply Voltage	-0.5 to +7.0	-0.5 to +7.0	V
VTERM	Terminal Voltage with Respect to GND	VCC + 0.5	VCC + 0.5	V
TA	Operating Temperature	0 to +70	-55 to +125	°C
TBIAS	Temperature Under Bias	-55 to +125	-65 to +135	°C
TSTG	Storage Temperature	-55 to +125	-65 to +150	°C
IOUT	DC Output Current	50	50	mA

NOTE:

2580 tbl 01

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0 MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Max.	Unit
CIN	Input Capacitance	VIN = 0V	10	pF
COUT	Output Capacitance	VOUT = 0V	12	pF

NOTE:

2580 tbl 04

1. This parameter is measured at characterization and not tested.

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MILITARY AND COMMERCIAL TEMPERATURE RANGES

DC ELECTRICAL CHARACTERISTICS(Commercial: $V_{CC} = 5.0V \pm 10\%$, $T_A = 0^\circ C$ to $+70^\circ C$; Military: $V_{CC} = 5V \pm 10\%$, $T_A = -55^\circ C$ to $+125^\circ C$)

Symbol	Parameter	Test Conditions ⁽¹⁾	Commercial			Military			Unit
			Min.	Typ. ⁽¹⁾	Max.	Min.	Typ. ⁽¹⁾	Max.	
V_{IH}	Input High Voltage	Guaranteed Logic High Level	2.0	—	—	2.0	—	—	V
V_{IL}	Input Low Voltage	Guaranteed Logic Low Level	—	—	0.8	—	—	0.8	V
$ I_{II} $	Input Leakage Current	$V_{CC} = \text{Max.}, V_{IN} = 0 \text{ to } V_{CC}$	—	—	10	—	—	10	μA
$ I_{LO} $	Output Leakage Current	$V_{CC} = \text{Max.}, \overline{OE} = 2.0V$ $V_{OUT} = 0 \text{ to } V_{CC}$	—	—	10	—	—	10	μA
I_{CC}	Operating Power Supply Current	$V_{CC} = \text{Max.}, \text{Outputs Disabled}$ $f = 10\text{MHz}^{(2)}$	—	40	80	—	40	100	mA
I_{CCQ1}	Quiescent Power Supply Current	$V_{IN} \geq V_{IH}, V_{IN} \leq V_{IL}$	—	20	40	—	20	50	mA
I_{CCQ2}	Quiescent Power Supply Current	$V_{IN} \geq V_{CC} - 0.2V, V_{IN} \leq 0.2V$	—	4	20	—	4	25	mA
$I_{CC}/f^{(2,3)}$	Increase in Power Supply Current	$V_{CC} = \text{Max.}, \text{Outputs Disabled}$	—	—	4	—	—	6	mA/MHz
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}, I_{OH} = -2.0\text{mA}$	2.4	—	—	2.4	—	—	V
$V_{OL}^{(4)}$	Output LOW Voltage	$V_{CC} = \text{Min.}, I_{OL} = 8\text{mA}$	—	—	0.4	—	—	0.4	V
I_{OS}	Output Short Circuit Current	$V_{CC} = \text{Max.}, V_O = \text{GND}$	-20	—	-120	-20	—	-120	mA

NOTES:

2580 1bl 03

1. Typical implies $V_{CC} = 5V$ and $T_A = +25^\circ C$.
2. I_{CC} is measured at 10MHz and $V_{IN} = 0$ to 3V. For frequencies greater than 10MHz, the following equation is used for the commercial range: $I_{CC} = 80 + 4(f - 10)\text{mA}$; for the military range, $I_{CC} = 100 + 6(f - 10)$. f = operating frequency in MHz, $f = 1/\text{t}_{\text{muc}}$ for IDT7216 and $f = 1/\text{t}_{\text{mc}}$ for IDT7217.
3. For frequencies greater than 10MHz, guaranteed by design, not production tested.
4. $I_{OL} = 4\text{mA}$ for $\text{t}_{\text{mc}} > 65\text{ns}$.

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MILITARY AND COMMERCIAL TEMPERATURE RANGES

AC ELECTRICAL CHARACTERISTICS COMMERCIAL ($V_{CC} = 5V \pm 10\%$, $T_A = 0^\circ$ to $+70^\circ C$)

Symbol	Parameter	7216L20 7217L20		7216L25 7217L25		7216L35 7217L35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
tMUC	Unclocked Multiply Time ⁽⁴⁾	2	30	2	38	2	55	ns
tMC	Clocked Multiply Time ⁽⁴⁾	2	20	2	25	2	35	ns
tS	X, Y, RND Set-up Time	11	—	12	—	12	—	ns
tH	X, Y, RND Hold Time	1	—	2	—	3	—	ns
tPWH	Clock Pulse Width High	9	—	10	—	10	—	ns
tPWL	Clock Pulse Width Low	9	—	10	—	10	—	ns
tPDSEL	MSPSEL to Product Out ⁽⁴⁾	2	18	2	20	2	25	ns
tPDP	Output Clock to P ⁽⁴⁾	2	18	2	20	2	25	ns
tPDY	Output Clock to Y ⁽⁴⁾	2	18	2	20	2	25	ns
tENA	3-State Enable Time	—	18	—	20	—	25	ns
tDIS	3-State Enable Time ⁽²⁾	—	18	—	20	—	22	ns
tS	Clock Enable Set-up Time (IDT7217 only)	10	—	10	—	10	—	ns
tH	Clock Enable Hold Time (IDT7217 only)	0	—	2	—	3	—	ns
tHCL	Clock Low Hold Time CLKXY Relative to CLKML (IDT7216 only) ^(1,3)	0	—	0	—	0	—	ns

Symbol	Parameter	7216L45 7217L45		7216L55 7217L55		7216L65 7217L65		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
tMUC	Unclocked Multiply Time ⁽⁴⁾	2	65	2	75	2	85	ns
tMC	Clocked Multiply Time ⁽⁴⁾	2	45	2	55	2	65	ns
tS	X, Y, RND Set-up Time	15	—	20	—	20	—	ns
tH	X, Y, RND Hold Time	3	—	3	—	3	—	ns
tPWH	Clock Pulse Width High	15	—	15	—	15	—	ns
tPWL	Clock Pulse Width Low	15	—	20	—	20	—	ns
tPDSEL	MSPSEL to Product Out ⁽⁴⁾	2	25	2	25	2	30	ns
tPDP	Output Clock to P ⁽⁴⁾	2	25	2	30	2	30	ns
tPDY	Output Clock to Y ⁽⁴⁾	2	25	2	30	2	30	ns
tENA	3-State Enable Time	—	25	—	30	—	35	ns
tDIS	3-State Enable Time ⁽²⁾	—	22	—	25	—	25	ns
tS	Clock Enable Set-up Time (IDT7217 only)	10	—	10	—	10	—	ns
tH	Clock Enable Hold Time (IDT7217 only)	3	—	3	—	3	—	ns
tHCL	Clock Low Hold Time CLKXY Relative to CLKML (IDT7216 only) ^(1,3)	0	—	0	—	0	—	ns

NOTES:

2580 tbl 06

1. To ensure that the correct product is entered in the output registers, new data may not be entered into the registers before the output registers have been clocked.
2. Transition is measured $\pm 500mV$ from steady state voltage.
3. Guaranteed by design, not production tested.
4. Minimum propagation delay times are guaranteed, not production tested.

IDT7216L, IDT7217L
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MILITARY AND COMMERCIAL TEMPERATURE RANGES

AC ELECTRICAL CHARACTERISTICS MILITARY (V_{CC} = 5V ± 10%, T_A = -55° to +125°C)

Symbol	Parameter	7216L25 7217L25		7216L30 7217L30		7216L40 7217L40		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{MUC}	Unlocked Multiply Time ⁽⁴⁾	2	38	2	43	2	60	ns
t _{MC}	Clocked Multiply Time ⁽⁴⁾	2	25	2	30	2	40	ns
t _S	X, Y, RND Set-up Time	12	—	12	—	15	—	ns
t _H	X, Y, RND Hold Time	2	—	2	—	3	—	ns
t _{PWH}	Clock Pulse Width High	10	—	10	—	15	—	ns
t _{PWL}	Clock Pulse Width Low	10	—	10	—	15	—	ns
t _{PDSEL}	MSPSEL to Product Out ⁽⁴⁾	2	20	2	20	2	25	ns
t _{PDP}	Output Clock to P ⁽⁴⁾	2	20	2	20	2	25	ns
t _{PDY}	Output Clock to Y ⁽⁴⁾	2	20	2	20	2	25	ns
t _{ENA}	3-State Enable Time	—	20	—	20	—	25	ns
t _{DIS}	3-State Enable Time ⁽²⁾	—	22	—	22	—	25	ns
t _S	Clock Enable Set-up Time (IDT7217 only)	10	—	10	—	12	—	ns
t _H	Clock Enable Hold Time (IDT7217 only)	2	—	2	—	3	—	ns
t _{HCL}	Clock Low Hold Time CLKXY Relative to CLKML (IDT7216 only) ^(1,3)	0	—	0	—	0	—	ns

Symbol	Parameter	7216L55 7217L55		7216L65 7217L65		7216L75 7217L75		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{MUC}	Unlocked Multiply Time ⁽⁴⁾	2	75	2	85	2	95	ns
t _{MC}	Clocked Multiply Time ⁽⁴⁾	2	55	2	65	2	75	ns
t _S	X, Y, RND Set-up Time	20	—	25	—	25	—	ns
t _H	X, Y, RND Hold Time	3	—	3	—	3	—	ns
t _{PWH}	Clock Pulse Width High	15	—	15	—	15	—	ns
t _{PWL}	Clock Pulse Width Low	15	—	15	—	15	—	ns
t _{PDSEL}	MSPSEL to Product Out ⁽⁴⁾	2	30	2	35	2	35	ns
t _{PDP}	Output Clock to P ⁽⁴⁾	2	30	2	30	2	35	ns
t _{PDY}	Output Clock to Y ⁽⁴⁾	2	30	2	30	2	35	ns
t _{ENA}	3-State Enable Time	—	25	—	35	—	40	ns
t _{DIS}	3-State Enable Time ⁽²⁾	—	25	—	25	—	25	ns
t _S	Clock Enable Set-up Time (IDT7217 only)	15	—	15	—	15	—	ns
t _H	Clock Enable Hold Time (IDT7217 only)	3	—	3	—	3	—	ns
t _{HCL}	Clock Low Hold Time CLKXY Relative to CLKML (IDT7216 only) ^(1,3)	0	—	0	—	0	—	ns

NOTES:

1. To ensure that the correct product is entered in the output registers, new data may not be entered into the registers before the output registers have been clocked.
2. Transition is measured ±500mV from steady state voltage.
3. Guaranteed by design, not production tested.
4. Minimum propagation delay times are guaranteed, not production tested.

2580 tbl 07

IDT7216L, IDT7217L
16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES

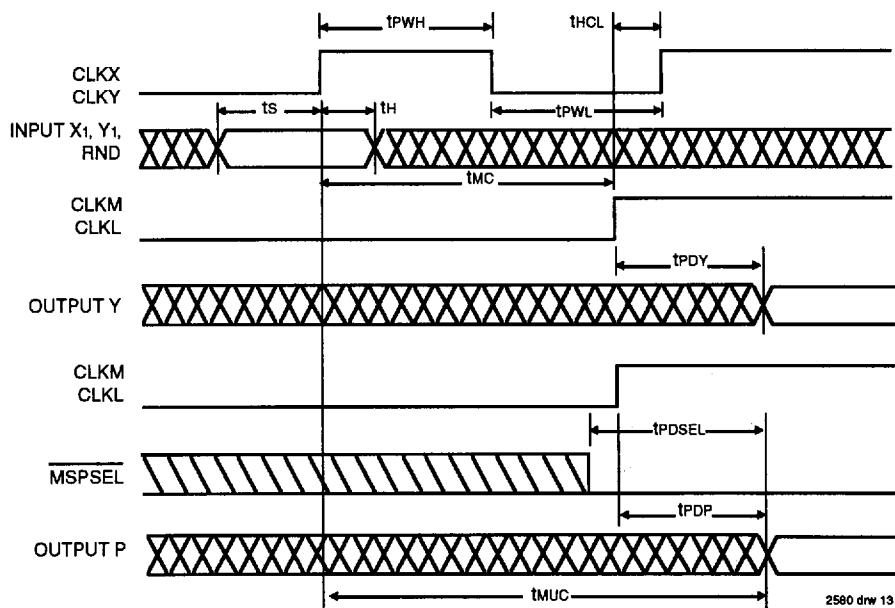


Figure 4. IDT7216 Timing Diagram

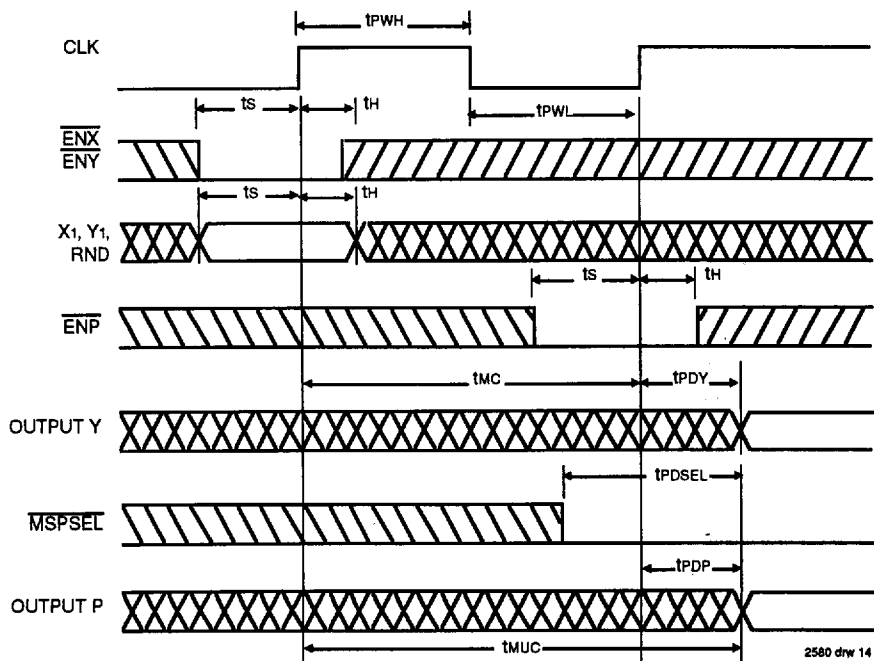


Figure 5. IDT7217 Timing Diagram

IDT7216L, IDT7217L
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MILITARY AND COMMERCIAL TEMPERATURE RANGES

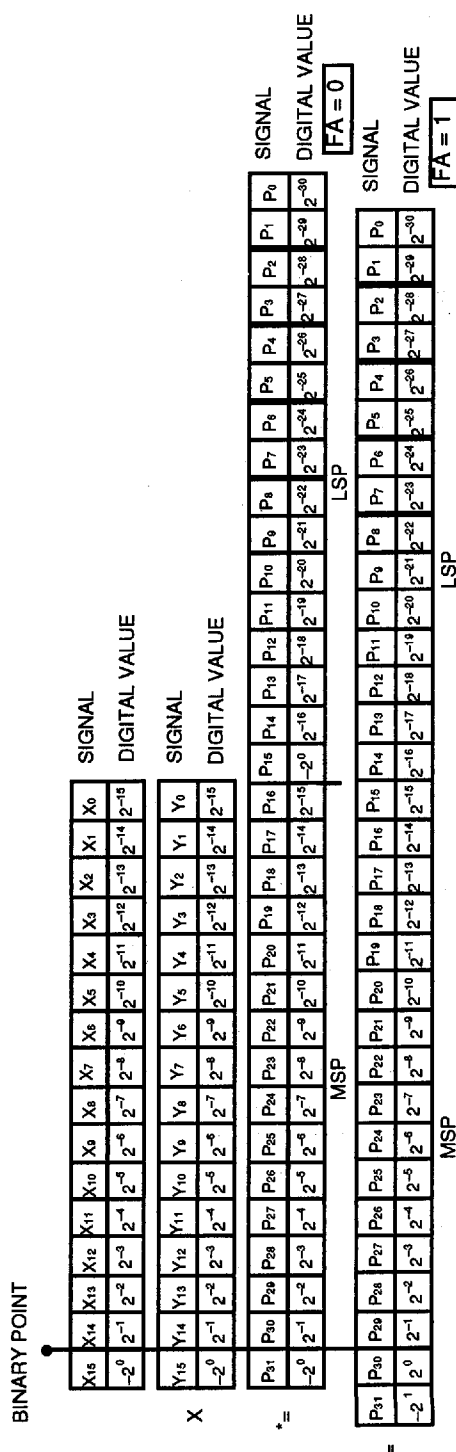


Figure 6. Fractional Two's Complement Notation

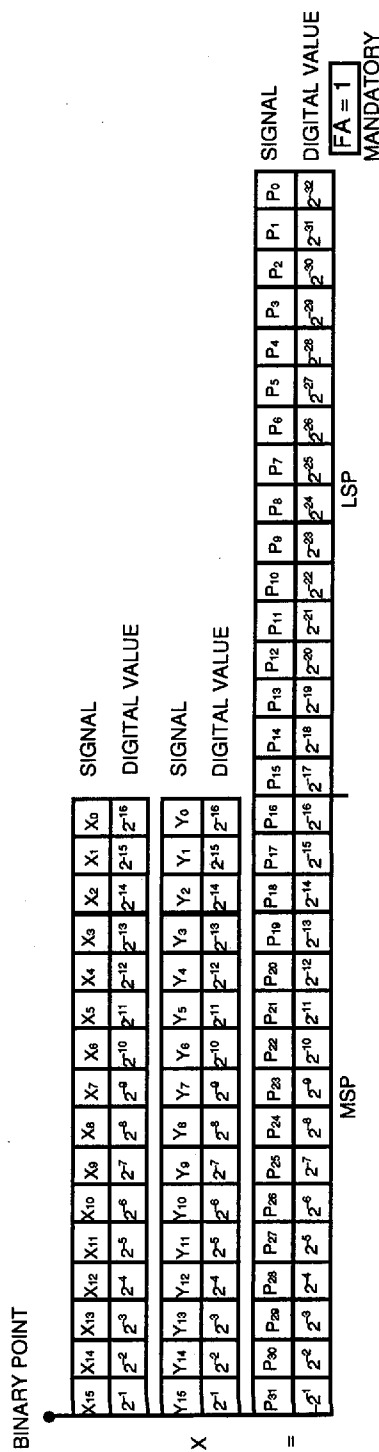


Figure 7. Fractional Unsigned Magnitude Notation

BINARY POINT

SIGNAL (TWO'S COMPLEMENT) DIGITAL VALUE															
X ₁₅	X ₁₄	X ₁₃	X ₁₂	X ₁₁	X ₁₀	X ₉	X ₈	X ₇	X ₆	X ₅	X ₄	X ₃	X ₂	X ₁	X ₀
-2 ⁰	2 ⁻¹	2 ⁻²	2 ⁻³	2 ⁻⁴	2 ⁻⁵	2 ⁻⁶	2 ⁻⁷	2 ⁻⁸	2 ⁻⁹	2 ⁻¹⁰	2 ⁻¹¹	2 ⁻¹²	2 ⁻¹³	2 ⁻¹⁴	2 ⁻¹⁵
SIGNAL (UNSIGNED MAGNITUDE) DIGITAL VALUE															
Y ₁₅	Y ₁₄	Y ₁₃	Y ₁₂	Y ₁₁	Y ₁₀	Y ₉	Y ₈	Y ₇	Y ₆	Y ₅	Y ₄	Y ₃	Y ₂	Y ₁	Y ₀
2 ⁻¹	2 ⁻²	2 ⁻³	2 ⁻⁴	2 ⁻⁵	2 ⁻⁶	2 ⁻⁷	2 ⁻⁸	2 ⁻⁹	2 ⁻¹⁰	2 ⁻¹¹	2 ⁻¹²	2 ⁻¹³	2 ⁻¹⁴	2 ⁻¹⁵	2 ⁻¹⁶
SIGNAL DIGITAL VALUE															
P ₃₁	P ₃₀	P ₂₉	P ₂₈	P ₂₇	P ₂₆	P ₂₅	P ₂₄	P ₂₃	P ₂₂	P ₂₁	P ₂₀	P ₁₉	P ₁₈	P ₁₇	P ₁₆
2 ⁰	2 ⁻¹	2 ⁻²	2 ⁻³	2 ⁻⁴	2 ⁻⁵	2 ⁻⁶	2 ⁻⁷	2 ⁻⁸	2 ⁻⁹	2 ⁻¹⁰	2 ⁻¹¹	2 ⁻¹²	2 ⁻¹³	2 ⁻¹⁴	2 ⁻¹⁵
SIGNAL DIGITAL VALUE															
P ₀	P ₁	P ₂	P ₃	P ₄	P ₅	P ₆	P ₇	P ₈	P ₉	P ₁₀	P ₁₁	P ₁₂	P ₁₃	P ₁₄	P ₁₅
2 ⁻¹⁶	2 ⁻¹⁵	2 ⁻¹⁴	2 ⁻¹³	2 ⁻¹²	2 ⁻¹¹	2 ⁻¹⁰	2 ⁻⁹	2 ⁻⁸	2 ⁻⁷	2 ⁻⁶	2 ⁻⁵	2 ⁻⁴	2 ⁻³	2 ⁻²	2 ⁻¹
SIGNAL DIGITAL VALUE															
P ₁₆	P ₁₇	P ₁₈	P ₁₉	P ₂₀	P ₂₁	P ₂₂	P ₂₃	P ₂₄	P ₂₅	P ₂₆	P ₂₇	P ₂₈	P ₂₉	P ₃₀	P ₃₁
2 ¹⁶	2 ¹⁷	2 ¹⁸	2 ¹⁹	2 ²⁰	2 ²¹	2 ²²	2 ²³	2 ²⁴	2 ²⁵	2 ²⁶	2 ²⁷	2 ²⁸	2 ²⁹	2 ³⁰	2 ³¹

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Figure 8. Fractional Mixed Mode Notation

BINARY POINT

SIGNAL DIGITAL VALUE															
X ₁₅	X ₁₄	X ₁₃	X ₁₂	X ₁₁	X ₁₀	X ₉	X ₈	X ₇	X ₆	X ₅	X ₄	X ₃	X ₂	X ₁	X ₀
2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
SIGNAL DIGITAL VALUE															
Y ₁₅	Y ₁₄	Y ₁₃	Y ₁₂	Y ₁₁	Y ₁₀	Y ₉	Y ₈	Y ₇	Y ₆	Y ₅	Y ₄	Y ₃	Y ₂	Y ₁	Y ₀
2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
SIGNAL DIGITAL VALUE															
P ₀	P ₁	P ₂	P ₃	P ₄	P ₅	P ₆	P ₇	P ₈	P ₉	P ₁₀	P ₁₁	P ₁₂	P ₁₃	P ₁₄	P ₁₅
2 ⁰	2 ¹	2 ²	2 ³	2 ⁴	2 ⁵	2 ⁶	2 ⁷	2 ⁸	2 ⁹	2 ¹⁰	2 ¹¹	2 ¹²	2 ¹³	2 ¹⁴	2 ¹⁵
SIGNAL DIGITAL VALUE															
P ₁₆	P ₁₇	P ₁₈	P ₁₉	P ₂₀	P ₂₁	P ₂₂	P ₂₃	P ₂₄	P ₂₅	P ₂₆	P ₂₇	P ₂₈	P ₂₉	P ₃₀	P ₃₁
2 ¹⁶	2 ¹⁷	2 ¹⁸	2 ¹⁹	2 ²⁰	2 ²¹	2 ²²	2 ²³	2 ²⁴	2 ²⁵	2 ²⁶	2 ²⁷	2 ²⁸	2 ²⁹	2 ³⁰	2 ³¹

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Figure 9. Integer Two's Complement Notation

* In this format an overflow occurs in the attempted multiplication of the two's complement number 1,000 ... 0 with 1,000.0 yielding an erroneous product of -1 in the fraction case and -2³⁰ in the integer case.

16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES



Figure 10. Integer Unsigned Magnitude Notation



Figure 11. Integer Mixed Mode Notation

IDT7216L, IDT7217L
16 x 16 PARALLEL CMOS MULTIPLIERS

MILITARY AND COMMERCIAL TEMPERATURE RANGES

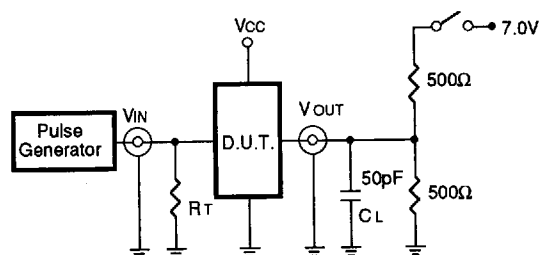


Figure 1. AC Test Load Circuit

AC TEST CONDITIONS

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	3ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	See Figure 1

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SWITCH POSITION

Test	Switch
Disable Low Enable Low	Closed
All Other Tests	Open

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

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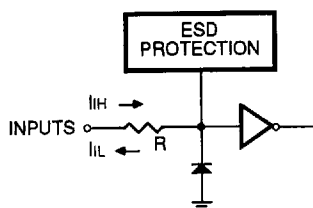


Figure 2. Input Interface Circuit

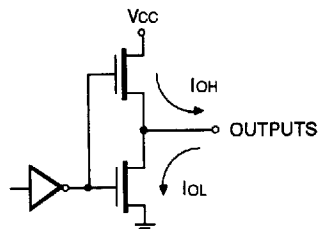


Figure 3. Output Interface Circuit